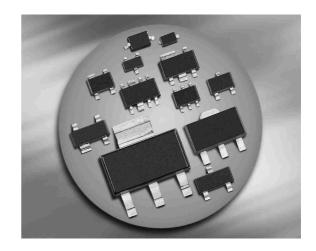


# **Silicon Switching Diode**

- For high-speed switching applications
- Series pair configuration



BAV99 BAV99F BAV99T BAV99W BAV99S BAV99U





Туре	Package	Configuration	Marking
BAV99	SOT23	series	A7s
BAV99F*	TSFP-3	series	A7s
BAV99S	SOT363	dual series	A7s
BAV99T	SC75	series	A7s
BAV99U	SC74	dual series	A7s
BAV99W	SOT323	series	A7s

<sup>\*</sup> Preliminary



**Maximum Ratings** at  $T_A = 25^{\circ}$ C, unless otherwise specified

Parameter	Symbol	Value	Unit
Diode reverse voltage	$V_{R}$	80	V
Peak reverse voltage	$V_{RM}$	85	
Forward current	I <sub>F</sub>	200	mA
Non-repetitive peak surge forward current	I <sub>FSM</sub>		А
<i>t</i> = 1 μs		4.5	
<i>t</i> = 1 ms		1	
t = 1  s, single		0.5	
t = 1  s, double		0.75	
Total power dissipation	P <sub>tot</sub>		mW
BAV99, <i>T</i> <sub>S</sub> ≤ 28°C		330	
BAV99F, $T_S \le \text{tbd}$		250	
BAV99S, <i>T</i> <sub>S</sub> ≤ 85°C		250	
BAV99T, <i>T</i> <sub>S</sub> ≤ 104°C		250	
BAV99U, <i>T</i> <sub>S</sub> ≤ 113°C		250	
BAV99W, $T_S \le 110^{\circ}$ C		250	
Junction temperature	$T_{\rm j}$	150	°C
Storage temperature	T <sub>stg</sub>	-65 150	

#### **Thermal Resistance**

Parameter	Symbol	Value	Unit
Junction - soldering point <sup>1)</sup>	R <sub>thJS</sub>		K/W
BAV99		≤ 360	
BAV99F		≤tbd	
BAV99S		≤ 260	
BAV99T		≤ 185	
BAV99U		≤ 150	
BAV99W		≤ 160	

 $<sup>^{1}\</sup>mbox{For calculation of}\,\mbox{$R_{\mbox{thJA}}$}$  please refer to Application Note Thermal Resistance



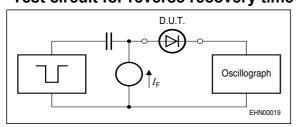
**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
DC Characteristics					
Breakdown voltage	$V_{(BR)}$	85	-	-	V
$I_{(BR)} = 100 \ \mu A$					
Reverse current	I <sub>R</sub>				μΑ
V <sub>R</sub> = 70 V		-	-	0.15	
$V_{\rm R}$ = 25 V, $T_{\rm A}$ = 150 °C		-	-	30	
$V_{\rm R}$ = 70 V, $T_{\rm A}$ = 150 °C		-	-	50	
Forward voltage	$V_{F}$				mV
I <sub>F</sub> = 1 mA		-	-	715	
<i>I</i> <sub>F</sub> = 10 mA		_	-	855	
$I_{\rm F}$ = 50 mA		_	-	1000	
I <sub>F</sub> = 100 mA		_	_	1200	
I <sub>F</sub> = 150 mA		_	_	1250	

**Electrical Characteristics** at  $T_A = 25$ °C, unless otherwise specified

Parameter	Symbol	Values			Unit
		min.	typ.	max.	
AC Characteristics					
Diode capacitance	C <sub>T</sub>	-	-	1.5	pF
$V_{R} = 0 \text{ V}, f = 1 \text{ MHz}$					
Reverse recovery time	t <sub>rr</sub>	-	-	4	ns
$I_{\rm F}$ = 10 mA, $I_{\rm R}$ = 10 mA, measured at $I_{\rm R}$ = 1mA,					
$R_{L}$ = 100 $\Omega$					

### Test circuit for reverse recovery time



Pulse generator:  $t_p$  = 100ns, D = 0.05,

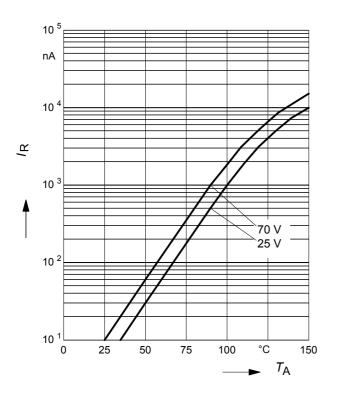
$$t_{\rm r}$$
 = 0.6ns,  $R_{\rm i}$  = 50 $\Omega$ 

Oscillograph: R = 50,  $t_r = 0.35$ ns



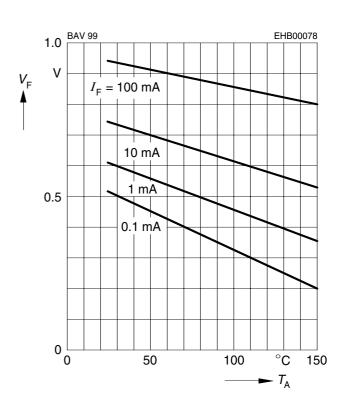
# Reverse current $I_R = f(T_A)$

 $V_{R}$  = Parameter



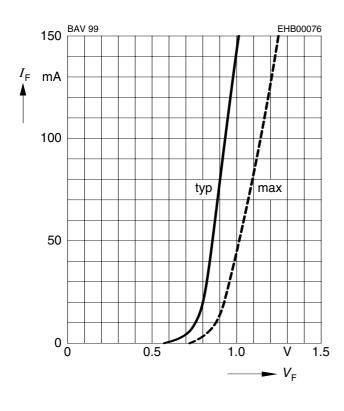
# Forward Voltage $V_F = f(T_A)$

 $I_{\mathsf{F}}$  = Parameter



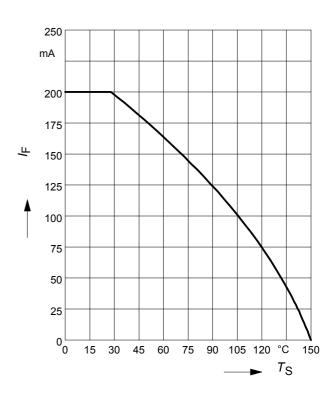
# Forward current $I_F = f(V_F)$

*T*<sub>A</sub> = 25°C



## Forward current $I_F = f(T_S)$

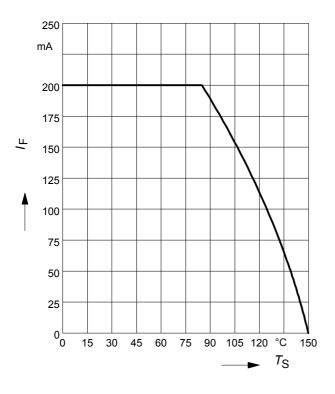
BAV99





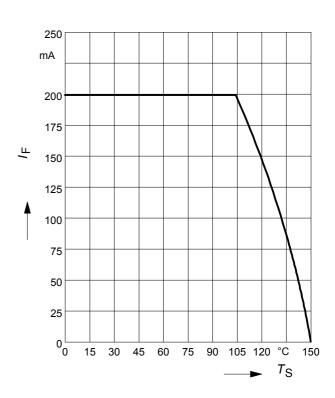
## Forward current $I_F = f(T_S)$

BAV99S



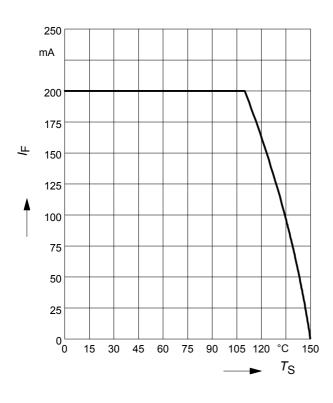
# Forward current $I_F = f(T_S)$

BAV99T



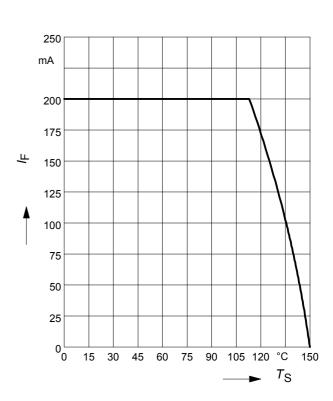
## Forward current $I_F = f(T_S)$

BAV99U



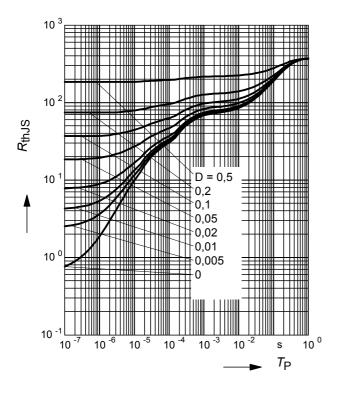
## Forward current $I_F = f(T_S)$

BAV99W



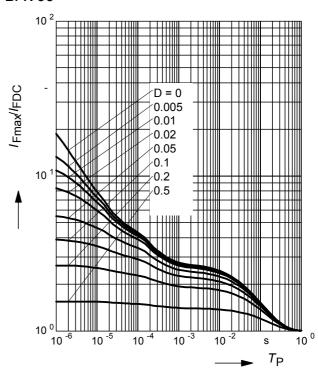


# Permissible Puls Load $R_{thJS} = f(t_p)$ BAV99

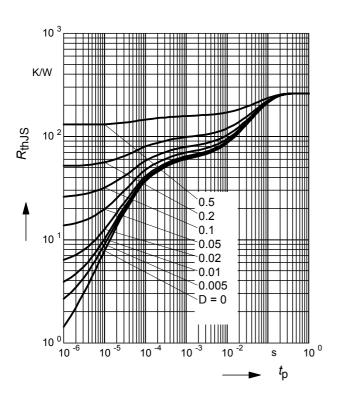


#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV99

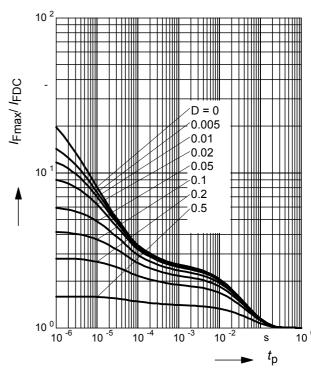


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAV99S



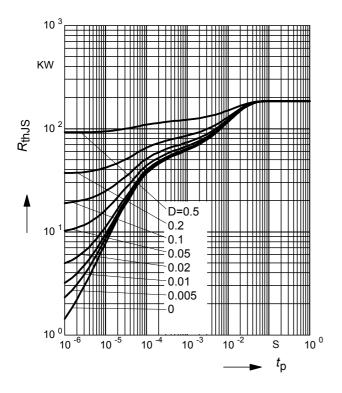
#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV99S



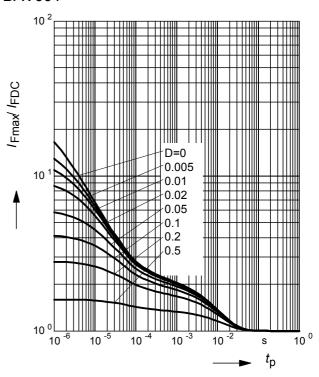


# Permissible Puls Load $R_{thJS} = f(t_p)$ BAV99T

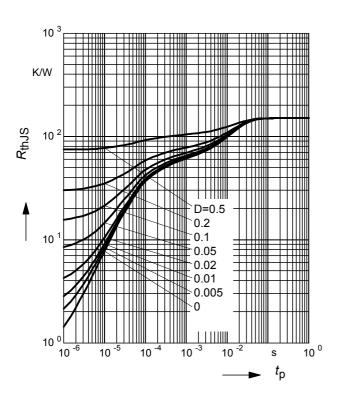


#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV99T

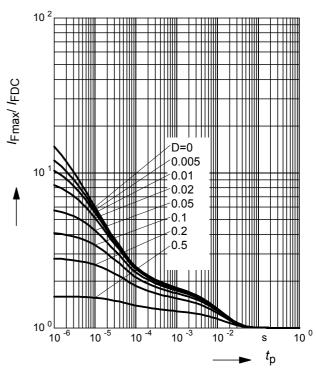


# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAV99U



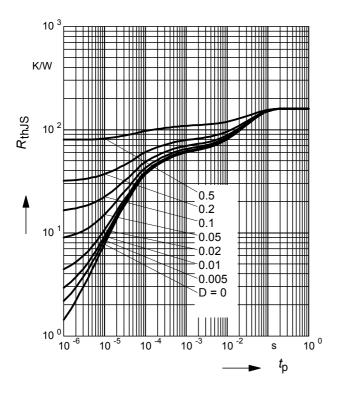
#### **Permissible Pulse Load**

 $I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$ BAV99U





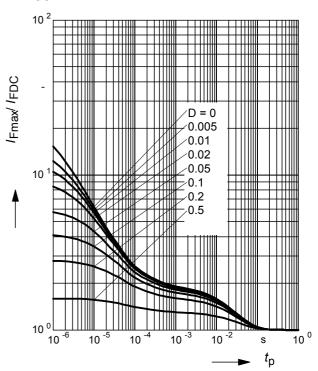
# **Permissible Puls Load** $R_{thJS} = f(t_p)$ BAV99W



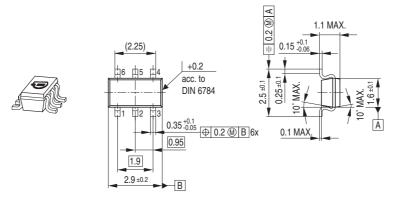
### **Permissible Pulse Load**

$$I_{\text{Fmax}}/I_{\text{FDC}} = f(t_{\text{p}})$$
  
BAV99W

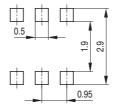
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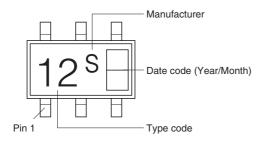


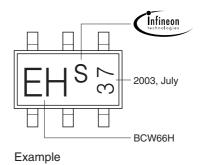


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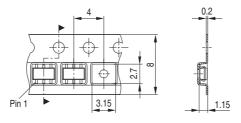


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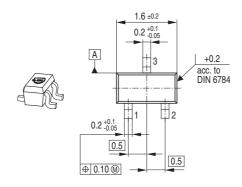


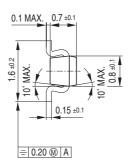


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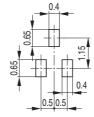




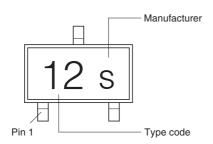


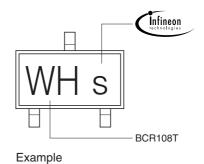


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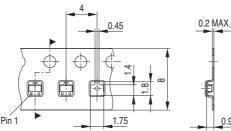


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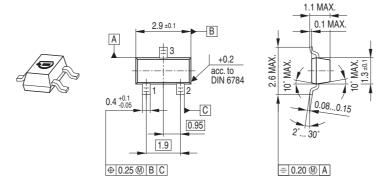




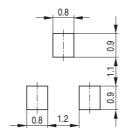
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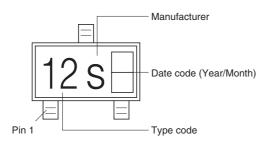


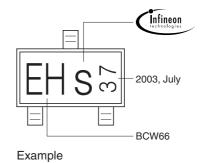


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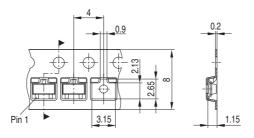


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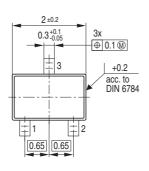


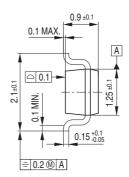
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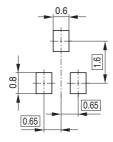




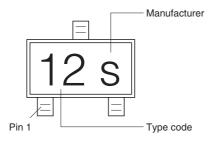


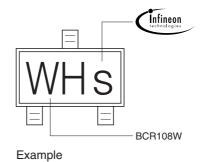


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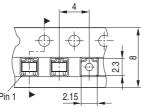


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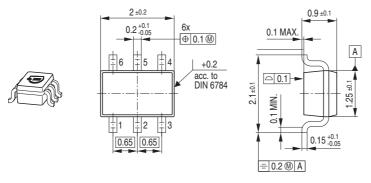


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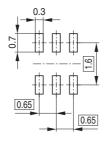




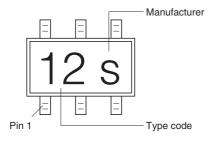


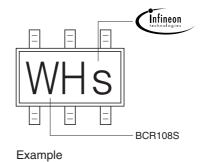


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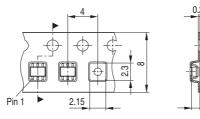


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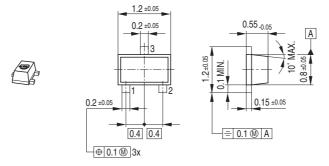




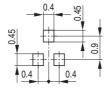
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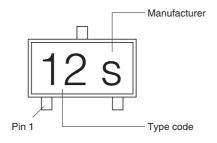


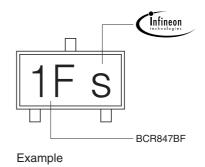


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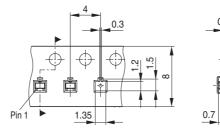


# Marking Layout





## Packing





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